

Thin Films Division Fachverband Dünne Schichten (DS)

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Overview of Invited Talks and Sessions

(Lecture halls H32 and H39; Poster E)

Invited Talks

DS 1.1	Mon	9:30–10:00	H32	Charge and ion exchange at electrochemical interfaces: atomistic insights by means of in-situ ellipsometry — ●CHRISTOPH COBET
DS 11.1	Tue	9:30–10:00	H32	Photoluminescence Analysis of Thin Films: What can it tell us about (Perovskite) Solar Cells? — ●THOMAS UNOLD
DS 11.3	Tue	10:15–10:45	H32	Defect activity in lead halide perovskite semiconductors — ●SILVIA MOTTI
DS 11.5	Tue	11:15–11:45	H32	Beyond traditional use of photoluminescence: Assessing halide perovskites quantitatively and qualitatively — ●CAROLIN SUTTER-FELLA
DS 11.7	Tue	12:00–12:30	H32	Photophysics of Sn-based hybrid perovskites — ●MARIA ANTONIETTA LOI
DS 15.1	Wed	9:30–10:00	H32	3D-Nanoprinting with Focused Electron Beams. Advances and Applications — ●ROBERT WINKLER, JASON D FOWLKES, JÜRGEN SATTELKOW, PHILIP D RACK, HARALD PLANK
DS 15.7	Wed	11:30–12:00	H32	Resist-free fabrication of graphene devices using focused ion beam patterning and direct-write ALD — ●AGEETH BOL
DS 19.1	Wed	15:00–15:30	H32	Fabrication of functional nanostructures by electron and ion beams — ●MILOS TOTH
DS 19.6	Wed	16:45–17:15	H32	Fundamentals of low-energy electron induced dissociation of focused electron beam induced deposition precursors — ●ODDUR INGÓLFSSON
DS 21.1	Thu	9:30–10:00	H32	Epitaxial graphene on SiC(0001) studied by electron spectroscopy and microscopy — ●FLORIAN SPECK
DS 21.6	Thu	11:15–11:45	H32	Patternable non-polar epigraphene for nanoelectronics and Dirac point physics — VLADIMIR PRUDKOVSKIY, YIRAN HU, HUE HU, LEI MA, CLAIRE BERGER, ●WALT DE HEER
DS 21.9	Thu	12:15–12:45	H32	Intrinsic stacking domains in graphene on silicon carbide: A pathway for intercalation — TOBIAS A DE JONG, EUGENE E KRASOVSKII, CHRISTIAN OTT, RUDOLF M TROMP, SENSE JAN VAN DER MOLEN, ●JOHANNES JOBST
DS 23.1	Thu	15:00–15:30	H32	Artificial nano-granular heterostructures: fundamentals and applications — ●OLEG UDALOV, IGOR BELOBORODOV
DS 23.5	Thu	16:30–17:00	H32	3D nanomagnetism and superconductivity: Current status and potential for future work — ●OLEKSANDR DOBROVOLSKIY, MICHAEL HUTH

Invited talks of the joint Symposium SKM Dissertation-Prize 2019

See SYSD for the full program of the symposium.

SYSD 1.1	Mon	9:30– 9:50	H2	Synchronization and Waves in Confined Complex Active Media — ●JAN FREDERIK TOTZ
SYSD 1.2	Mon	9:50–10:10	H2	Spin scattering of topologically protected electrons at defects — ●PHILIPP RÜSSMANN
SYSD 1.3	Mon	10:10–10:30	H2	Beyond the molecular movie: Revealing the microscopic processes behind photo-induced phase transitions — ●CHRIS W. NICHOLSON
SYSD 1.4	Mon	10:30–10:50	H2	Thermodynamic bounds on current fluctuations — ●PATRICK PIETZONKA
SYSD 1.5	Mon	10:50–11:10	H2	Lightwave-driven quasiparticle acceleration — ●FABIAN LANGER

SYSD 1.6	Mon	11:10–11:30	H2	Ultrafast plasmon-driven point-projection electron microscopy — ●JAN VOGELSANG
SYSD 1.7	Mon	11:30–11:50	H2	Helimagnets, sand patterns and fingerprints linked by topology — ●PEGGY SCHÖNHERR

Invited talks of the joint Symposium Mechanically Controlled Electrical Conductivity of Oxides

See SYCO for the full program of the symposium.

SYCO 1.1	Mon	9:30–10:00	H1	Dislocation Dynamics and Their Conductivities in Oxides — ●YUICHI IKUHARA
SYCO 1.2	Mon	10:00–10:30	H1	Strain effects in ionic conductivity and electrode processes — ●JÜRGEN JANEK
SYCO 1.3	Mon	10:30–11:00	H1	Elastic dipoles of point defects in materials — ●CELINE VARVENNE
SYCO 1.4	Mon	11:30–12:00	H1	Mapping strain/pressure with ZnO nanowire arrays by piezophototronic effect — ●CAOFENG PAN
SYCO 1.5	Mon	12:00–12:30	H1	Bulk and Flexo-photovoltaic effect — ●MARIN ALEXE

Invited talks of the joint Symposium Patterns in Nature: Origins, Universality, Functions

See SYPN for the full program of the symposium.

SYPN 1.1	Mon	15:00–15:30	H1	Engineering spatial-temporal organization of bacterial suspensions — ●IGOR ARONSON
SYPN 1.2	Mon	15:30–16:00	H1	Collective behaviour and pattern formation in phoretic active matter — ●RAMIN GOLESTANIAN
SYPN 1.3	Mon	16:00–16:30	H1	Control and selection of spatio-temporal patterns in complex systems — ●SVETLANA GUREVICH
SYPN 1.4	Mon	16:45–17:15	H1	Self-organization of Active Surfaces — ●FRANK JÜLICHER
SYPN 1.5	Mon	17:15–17:45	H1	Front instabilities can reverse desertification — ●EHUD MERON

Invited talks of the joint Symposium Geometry, Topology, and Condensed Matter

See SYGT for the full program of the symposium.

SYGT 1.1	Tue	9:30–10:00	H1	Thermal Properties of Vortices on Curved Surfaces — ●JOSÉ LORENZANA
SYGT 1.2	Tue	10:00–10:30	H1	Curvature-induced effects in manomagnets — ●DENIS SHEKA
SYGT 1.3	Tue	10:30–11:00	H1	Magnetization configurations and reversal of individual ferromagnetic nanotubes — ●MARTINO POGGIO
SYGT 1.4	Tue	11:15–11:45	H1	An experimental perspective on topology and nanoelectronics in graphene and related 2D materials. — ●IVAN J. VERA-MARUN
SYGT 1.5	Tue	11:45–12:15	H1	Roles of the curvature in two-dimensional nematic films — ●GAETANO NAPOLI

Invited talks of the joint Symposium Interaction Effects and Correlations in twodimensional Systems - New Challenges for Theory

See SYTS for the full program of the symposium.

SYTS 1.1	Wed	15:00–15:30	H1	Spectra of layered semiconductors from many-body perturbation theory — ●MICHAEL ROHLFING
SYTS 1.2	Wed	15:30–16:00	H1	Dark exciton dynamics in 2D materials — ●ERMIN MALIC
SYTS 1.3	Wed	16:00–16:30	H1	Excitons versus electron-hole plasma in monolayer transition metal dichalcogenide semiconductors — ●ALEXANDER STEINHOFF
SYTS 1.4	Wed	16:45–17:15	H1	Theory of near K-point optical properties of TMDC multilayers — ●TINEKE STROUCKEN
SYTS 1.5	Wed	17:15–17:45	H1	High-throughput modeling and discovery of novel 2D materials — ●KRISTIAN THYGESEN

Invited talks of the joint Symposium Czech Republic as Guest of Honor

See SYCZ for the full program of the symposium.

SYCZ 1.1	Thu	9:30–10:00	H4	Crystal symmetries and transport phenomena in antiferromagnets — •TOMAS JUNGWIRTH
SYCZ 1.2	Thu	10:00–10:30	H4	Terahertz subcycle charge and spin control — •RUPERT HUBER
SYCZ 1.3	Thu	10:30–11:00	H4	1D molecular system on surfaces — •PAVEL JELINEK
SYCZ 1.4	Thu	11:15–11:45	H4	Tunneling microscopy on insulators provides access to out-of-equilibrium charge states — •JASCHA REPP
SYCZ 1.5	Thu	11:45–12:15	H4	Occam’s razor and complex networks from brain to climate — •JAROSLAV HLINKA
SYCZ 1.6	Thu	12:15–12:45	H4	Long range temporal correlations in complex systems — •HOLGER KANTZ

Invited talks of the joint Symposium Identifying Optimal Physical Implementations for beyond von Neumann Computing Concepts

See SYCC for the full program of the symposium.

SYCC 1.1	Fri	9:30–10:00	H1	On the Link Between Energy and Information for the Design of Neuro-morphic Systems — •NARAYAN SRINIVASA
SYCC 1.2	Fri	10:00–10:30	H1	Encoding neural and synaptic functionalities in electron spin: A pathway to efficient neuromorphic computing — •KAUSHIK ROY
SYCC 1.3	Fri	10:30–11:00	H1	Neuromorphic computing with spintronic nano-oscillators — •PHILIPPE TALATCHIAN
SYCC 1.4	Fri	11:15–11:45	H1	Artificial Intelligence and beyond von Neumann architectures, a mutual opportunity — •MIRKO PREZIOSO
SYCC 1.5	Fri	11:45–12:15	H1	Brain-inspired approaches in ultrafast magnetism — •JOHAN H. MENTINK

Sessions

DS 1.1–1.7	Mon	9:30–11:45	H32	Optical Analysis of Thin Films I (Reflection, Ellipsometry, Raman, IR-DUV Spectroscopy, ...
DS 2.1–2.6	Mon	9:30–12:45	H34	Focus Session: Oxide Semiconductors for Novel Devices (joint session HL/DS)
DS 3.1–3.12	Mon	9:30–12:45	H39	Layer Properties: Electronic, Optical and Mechanical Properties
DS 4.1–4.9	Mon	10:30–13:00	H9	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge I (joint session O/TT/CPP/DS)
DS 5.1–5.1	Mon	12:30–13:00	H32	Prize talk Selina Olthof (joint session PRV/DS/VA)
DS 6.1–6.10	Mon	15:00–17:30	H9	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge II (joint session O/TT/DS/CPP)
DS 7.1–7.5	Mon	15:00–16:15	H32	Optical Analysis of Thin Films II (Reflection, Ellipsometry, Raman, IR-DUV Spectroscopy, ...
DS 8.1–8.4	Mon	15:00–16:30	PHY 5.0.21	Instrumentation Micro-/Nano-Analysis and Lithography/Structuring (joint session KFM/DS/O)
DS 9.1–9.6	Mon	15:00–16:30	H39	Layer Deposition (ALD, MBE, Sputtering, ...)
DS 10.1–10.5	Mon	16:45–18:00	H39	Thermoelectric and Phase Change Materials
DS 11.1–11.9	Tue	9:30–13:15	H32	PhD-Symposium: Photoluminescence of halide perovskites: What does it tell us and what not? (joint session DS/AKjDPG/HL)
DS 12.1–12.9	Tue	10:30–13:00	H9	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge III (joint session O/CPP/DS/TT)
DS 13.1–13.10	Tue	14:00–16:45	H9	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge IV (joint session O/CPP/DS/TT)
DS 14.1–14.60	Tue	17:00–20:00	Poster E	Poster
DS 15.1–15.9	Wed	9:30–12:30	H32	Focus Session: Direct-Write Nanofabrication and Applications I (Electron Beam Induced Processing) (joint session DS/TT)
DS 16.1–16.11	Wed	9:30–12:30	H39	Organic Thin Films, Organic-Inorganic Interfaces

DS 17.1–17.9	Wed	10:30–13:15	H9	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge V (joint session O/CPP/DS/TT)
DS 18.1–18.11	Wed	15:00–17:45	H9	
DS 19.1–19.9	Wed	15:00–18:00	H32	Frontiers of Electronic-Structure Theory: Focus on the Interface Challenge VI (joint session O/DS/CPP/TT)
DS 20	Wed	18:30–19:30	H39	Focus Session: Direct-Write Nanofabrication and Applications II
DS 21.1–21.9	Thu	9:30–12:45	H32	(Electron Beam Induced Processing) (joint session DS/TT)
DS 22.1–22.10	Thu	9:30–12:15	H39	Annual General Meeting of the Thin Films Division
DS 23.1–23.8	Thu	15:00–17:45	H32	Focus Session: Growth, Properties and Application of Epitaxial Graphene (joint session DS/O/HL)
DS 24.1–24.12	Thu	15:00–18:15	H39	Thin Film Applications
DS 25.1–25.12	Fri	9:30–12:45	H32	Direct-Write Nanofabrication and Applications III
				(Electron Beam Induced Processing) (joint session DS/TT)
				Thin Film Properties: Structure, Morphology and Composition (XRD, TEM, XPS, SIMS, RBS, AFM, ...) Part I
				Thin Film Properties: Structure, Morphology and Composition (XRD, TEM, XPS, SIMS, RBS, AFM, ...) Part II

Annual General Meeting of the Thin Films Division

Wednesday 18:30–19:30 H39